



**THE DATASHEET OF**  
**2N6403G**



# 2N6400 Series

## Silicon Controlled Rectifiers

### Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies; or wherever half-wave silicon gate-controlled, solid-state devices are needed.

#### Features

- Glass Passivated Junctions with Center Gate Geometry for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 V
- These are Pb-Free Devices

#### MAXIMUM RATINGS\* ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) ( $T_J = -40$ to $125^\circ\text{C}$ , Sine Wave 50 to 60 Hz; Gate Open)	$V_{\text{DRM}}$ , $V_{\text{RRM}}$	50 100 200 400 600 800	V
On-State Current RMS (180° Conduction Angles; $T_C = 100^\circ\text{C}$ )	$I_{\text{T(RMS)}}$	16	A
Average On-State Current (180° Conduction Angles; $T_C = 100^\circ\text{C}$ )	$I_{\text{T(AV)}}$	10	A
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_J = 25^\circ\text{C}$ )	$I_{\text{TSM}}$	160	A
Circuit Fusing Considerations ( $t = 8.3$ ms)	$I^2t$	145	$\text{A}^2\text{s}$
Forward Peak Gate Power (Pulse Width $\leq 1.0$ $\mu\text{s}$ , $T_C = 100^\circ\text{C}$ )	$P_{\text{GM}}$	20	W
Forward Average Gate Power ( $t = 8.3$ ms, $T_C = 100^\circ\text{C}$ )	$P_{\text{G(AV)}}$	0.5	W
Forward Peak Gate Current (Pulse Width $\leq 1.0$ $\mu\text{s}$ , $T_C = 100^\circ\text{C}$ )	$I_{\text{GM}}$	2.0	A
Operating Junction Temperature Range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{\text{stg}}$	-40 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1.  $V_{\text{DRM}}$  and  $V_{\text{RRM}}$  for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



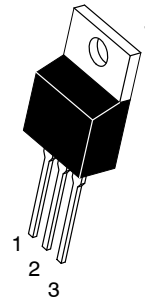
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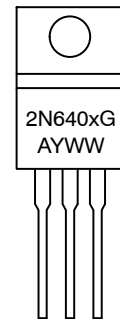
**SCRs**  
**16 AMPERES RMS**  
**50 thru 800 VOLTS**



#### MARKING DIAGRAM



**TO-220AB**  
**CASE 221A**  
**STYLE 3**



x = 0, 1, 2, 3, 4 or 5  
A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package

#### PIN ASSIGNMENT

Pin	Assignment
1	Cathode
2	Anode
3	Gate
4	Anode

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

## 2N6400 Series

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.5	$^{\circ}\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes 1/8 in from Case for 10 Seconds	$T_L$	260	$^{\circ}\text{C}$

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

*Peak Repetitive Forward or Reverse Blocking Current ( $V_{AK} = \text{Rated } V_{DRM}$ or $V_{RRM}$ , Gate Open)	$T_J = 25^{\circ}\text{C}$	$I_{DRM}$	-	-	10	$\mu\text{A}$
	$T_J = 125^{\circ}\text{C}$	$I_{RRM}$	-	-	2.0	mA

### ON CHARACTERISTICS

*Peak Forward On-State Voltage ( $I_{TM} = 32$ A Peak, Pulse Width $\leq 1$ ms, Duty Cycle $\leq 2\%$ )		$V_{TM}$	-	-	1.7	V
*Gate Trigger Current (Continuous dc) ( $V_D = 12$ Vdc, $R_L = 100 \Omega$ )	$T_C = 25^{\circ}\text{C}$	$I_{GT}$	-	9.0	30	mA
	$T_C = -40^{\circ}\text{C}$		-	-	60	
*Gate Trigger Voltage (Continuous dc) ( $V_D = 12$ Vdc, $R_L = 100 \Omega$ )	$T_C = 25^{\circ}\text{C}$	$V_{GT}$	-	0.7	1.5	V
	$T_C = -40^{\circ}\text{C}$		-	-	2.5	
Gate Non-Trigger Voltage ( $V_D = 12$ Vdc, $R_L = 100 \Omega$ ), $T_C = +125^{\circ}\text{C}$		$V_{GD}$	0.2	-	-	V
*Holding Current ( $V_D = 12$ Vdc, Initiating Current = 200 mA, Gate Open)	$T_C = 25^{\circ}\text{C}$	$I_H$	-	18	40	mA
	* $T_C = -40^{\circ}\text{C}$		-	-	60	
Turn-On Time ( $I_{TM} = 16$ A, $I_{GT} = 40$ mAdc, $V_D = \text{Rated } V_{DRM}$ )		$t_{gt}$	-	1.0	-	$\mu\text{s}$
Turn-Off Time ( $I_{TM} = 16$ A, $I_R = 16$ A, $V_D = \text{Rated } V_{DRM}$ )	$T_C = 25^{\circ}\text{C}$	$t_q$	-	15	-	$\mu\text{s}$
	$T_J = +125^{\circ}\text{C}$		-	35	-	

### DYNAMIC CHARACTERISTICS

Critical Rate-of-Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}$ , Exponential Waveform) $T_J = +125^{\circ}\text{C}$	$dv/dt$	-	50	-	$\text{V}/\mu\text{s}$
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\*Indicates JEDEC Registered Data.

# 2N6400 Series

## Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Off State Forward Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Off State Reverse Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Peak On State Voltage
$I_H$	Holding Current

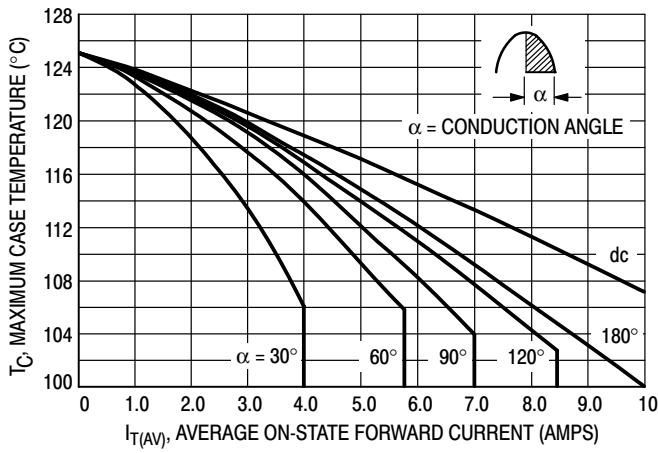
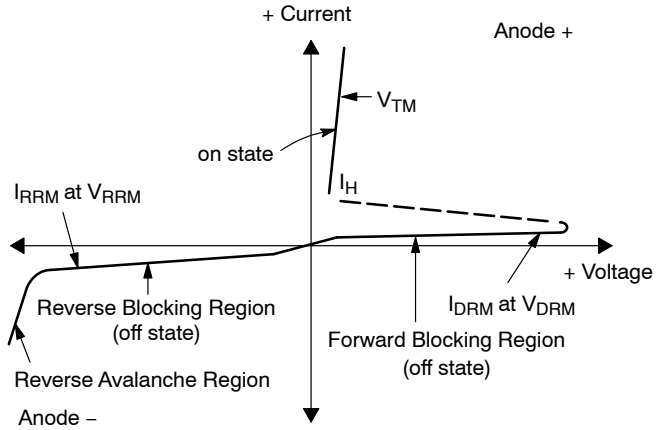


Figure 1. Average Current Derating

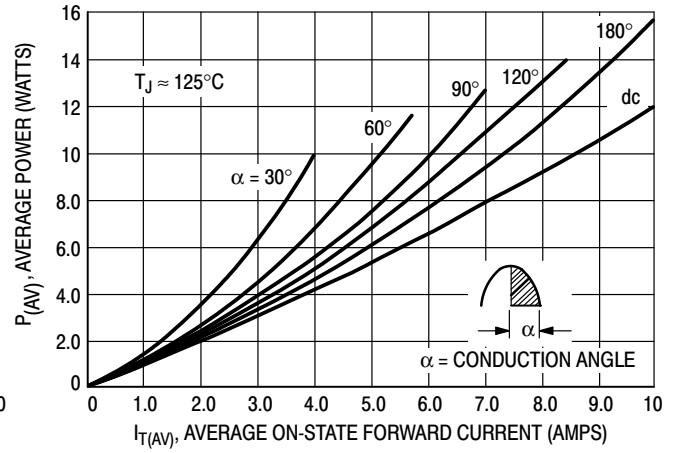


Figure 2. Maximum On-State Power Dissipation

# 2N6400 Series

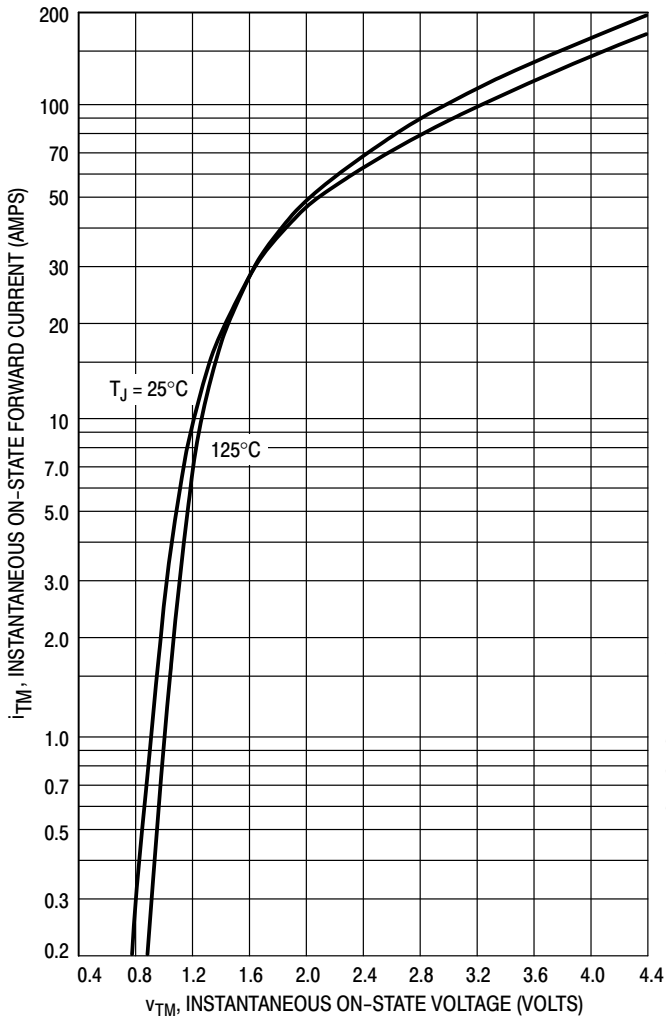


Figure 3. On-State Characteristics

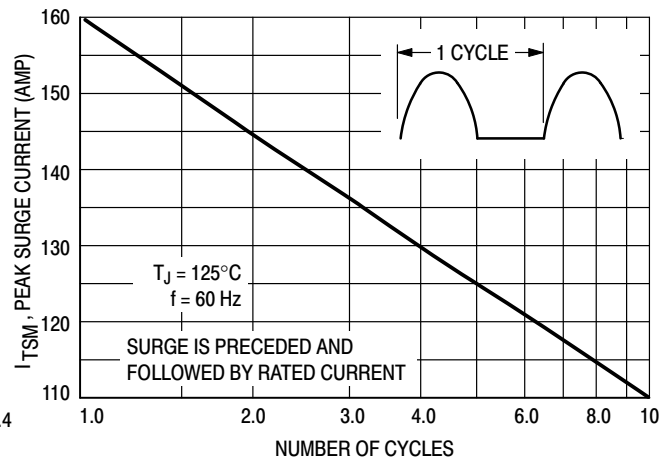


Figure 4. Maximum Non-Repetitive Surge Current

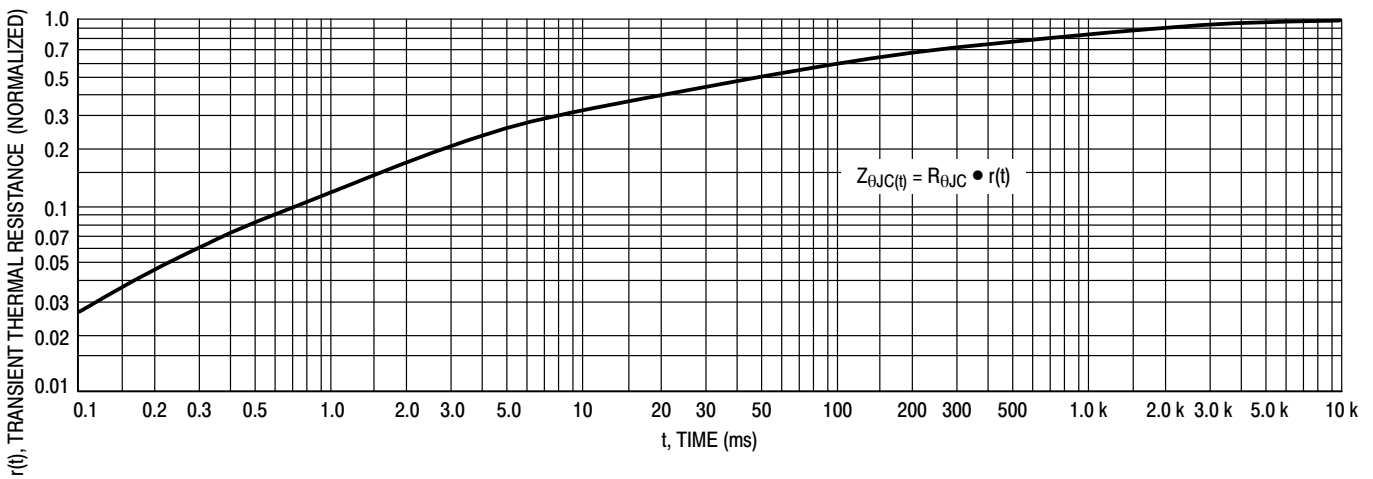
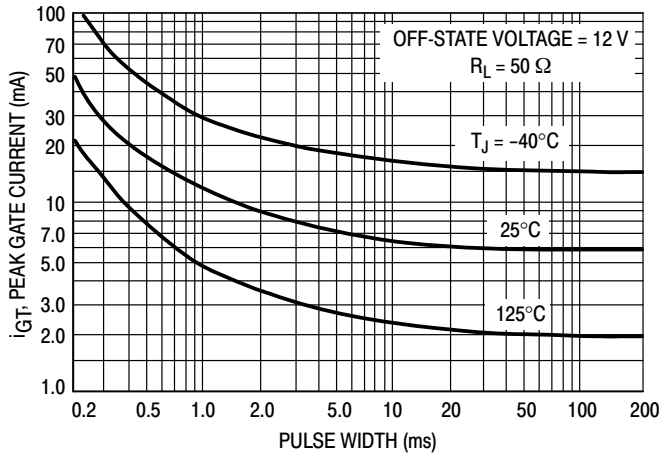


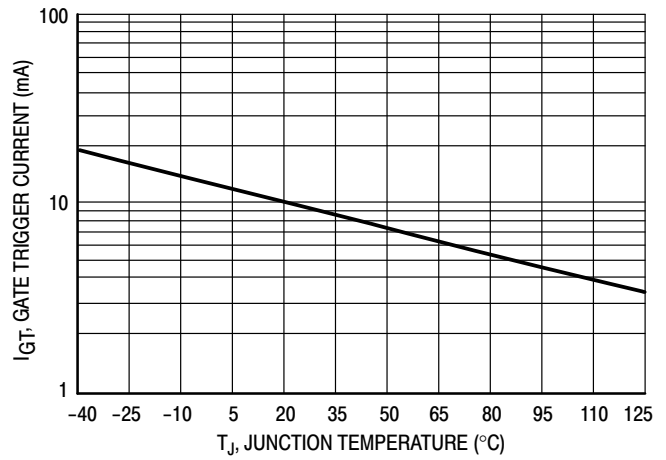
Figure 5. Thermal Response

# 2N6400 Series

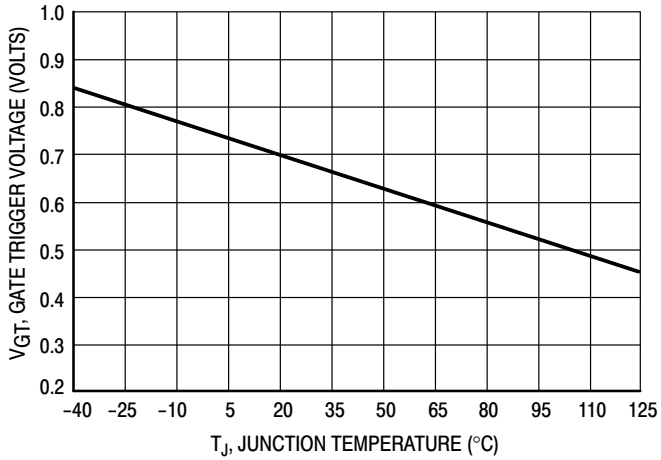
## TYPICAL CHARACTERISTICS



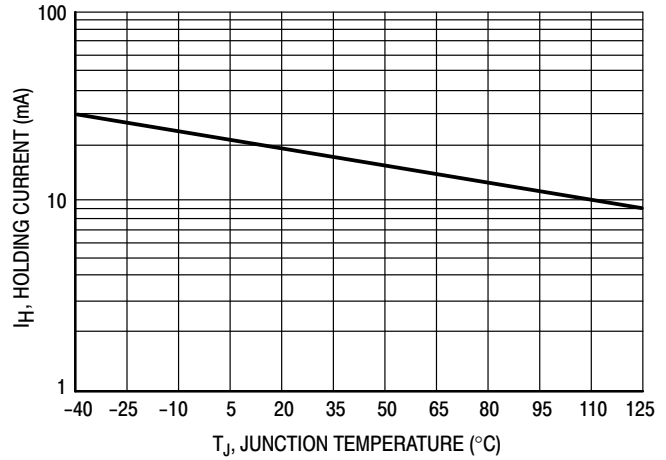
**Figure 6. Typical Gate Trigger Current versus Pulse Width**



**Figure 7. Typical Gate Trigger Current versus Junction Temperature**



**Figure 8. Typical Gate Trigger Voltage versus Junction Temperature**



**Figure 9. Typical Holding Current versus Junction Temperature**

## 2N6400 Series

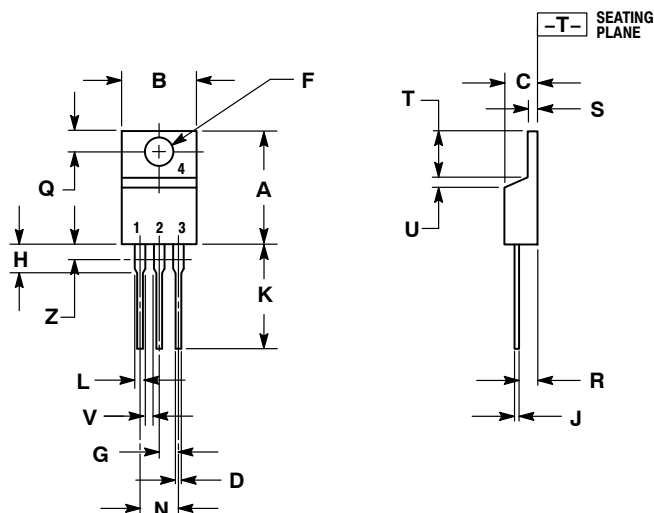
### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
2N6400G	TO-220AB (Pb-Free)	500 Units / Box
2N6401G	TO-220AB (Pb-Free)	
2N6402G	TO-220AB (Pb-Free)	
2N6403G	TO-220AB (Pb-Free)	
2N6403TG	TO-220AB (Pb-Free)	50 Units / Rail
2N6404G	TO-220AB (Pb-Free)	500 Units / Box
2N6405G	TO-220AB (Pb-Free)	

# 2N6400 Series

## PACKAGE DIMENSIONS

### TO-220 CASE 221A-07 ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 3:

1. CATHODE
2. ANODE
3. GATE
4. ANODE

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